

PD412PI

Compact Package Type Photodiode with Condensing Lens

■ Features

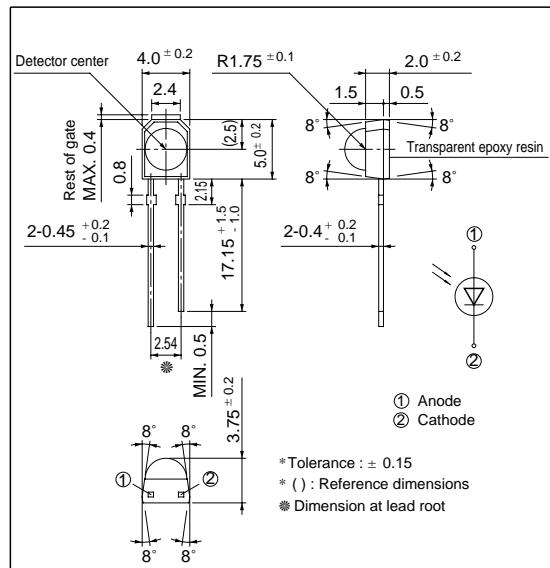
1. High sensitivity
(TYP. 0.5A/W at $\lambda_p = 780\text{nm}$)
 2. High speed response

■ Applications

1. Optoelectronic switches
 2. MD (mini disk) laser power monitors

■ Outline Dimensions

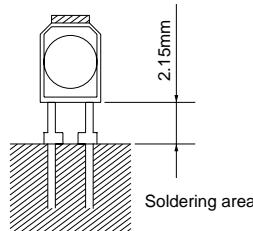
(Unit : mm)



■ Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Reverse voltage	V _R	32	V
Power dissipation	P	150	mW
Operating temperature	T _{opr}	- 25 to +85	°C
Storage temperature	T _{stg}	- 40 to +100	°C
* ¹ Soldering temperature	T _{sol}	260	°C



*1 For MAX 5 seconds at the position of 2.15 mm from the resin edge

"In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device."

■ Electro-optical Characteristics

(Ta=25 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Shortcircuit current	I _{SC}	* ² E _V = 100 lx	3.5	4.7	6.3	μ A
Shortcircuit current temperature coefficient	β _T	* ² E _V = 100 lx	-	0.2	-	% /°C
Dark current	I _D	V _R = 10V, E _e = 0	-	0.5	10	nA
Dark current temperature coefficient	α _T	V _R = 10V, E _e = 0	-	3.5	5.0	times/10°C
Terminal capacitance	C _t	V _R = 3V, f= 1MHz	-	100	350	pF
Peak sensitivity wavelength	λ _P		-	800	-	nm
Peak spectral sensitivity	K	I = 780nm	-	0.5	-	A/W
Response time	Rise Time	t _r	R _L = 1kΩ	-	250	-
	Fall Time	t _f	V _R = 10V	-	250	-
Half intensity angle	Δθ		-	± 45	-	°

*²E_V : Illuminance by CIE standard light source A (tungsten lamp)

Fig. 1 Power Dissipation vs. Ambient Temperature

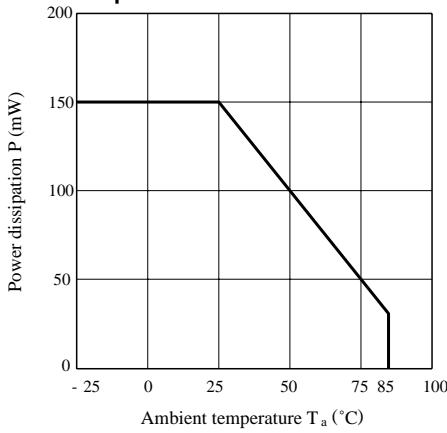


Fig. 2 Shortcircuit Current vs. Illuminance

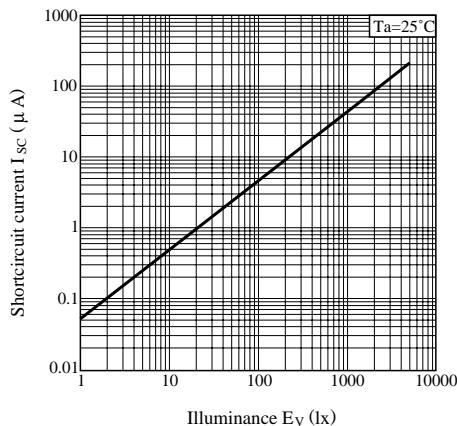
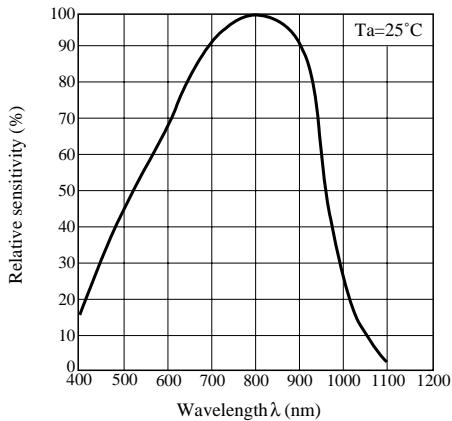
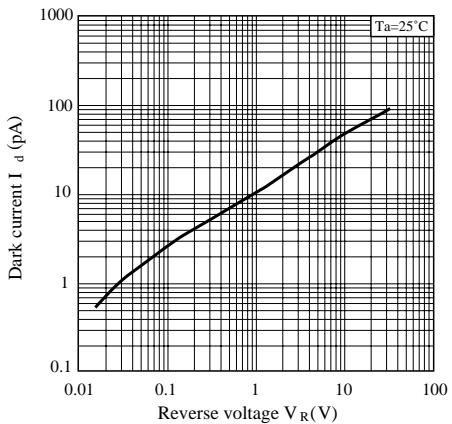
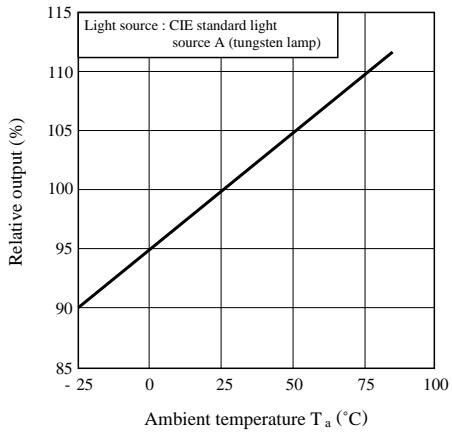
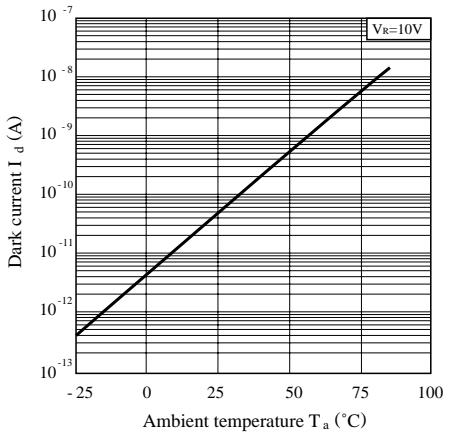
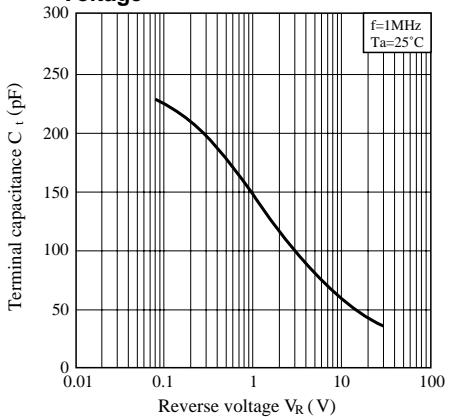
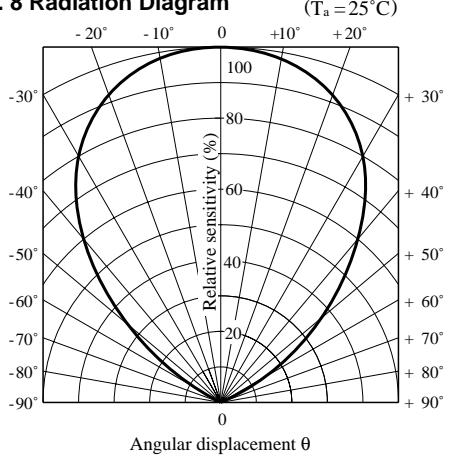


Fig. 3 Spectral Sensitivity**Fig. 5 Dark Current vs. Reverse Voltage****Fig. 7 Relative Output vs. Ambient Temperature****Fig. 4 Dark Current vs. Ambient Temperature****Fig. 6 Terminal Capacitance vs. Reverse Voltage****Fig. 8 Radiation Diagram**

**Fig. 9 Relative Output vs. Distance
(Detector : GL537/GL538)**

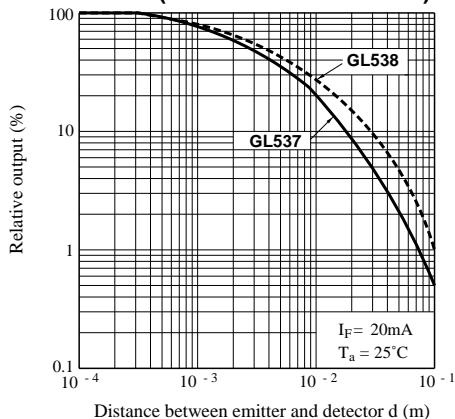
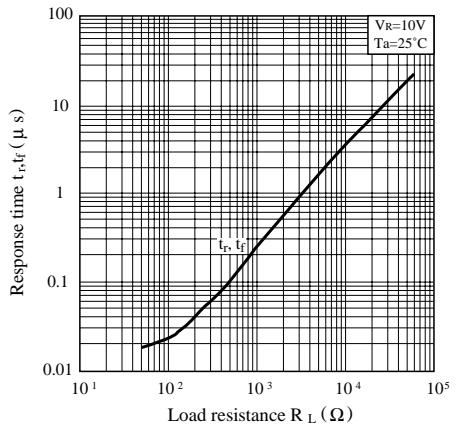
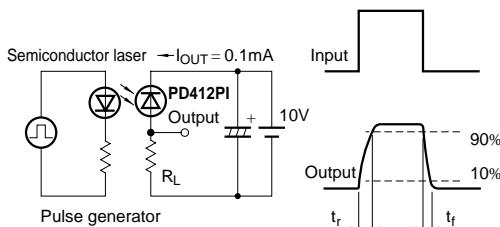


Fig. 10 Response Time vs. Load Resistance



Test Circuit for Response Time



- Please refer to the chapter "Precautions for Use". (Page 78 to 93)